

Electronic Supporting Information for

**Pt Complex Based Terpolymer Acceptors Linked Through Ancillary Ligand for All-Polymer
Solar Cells**

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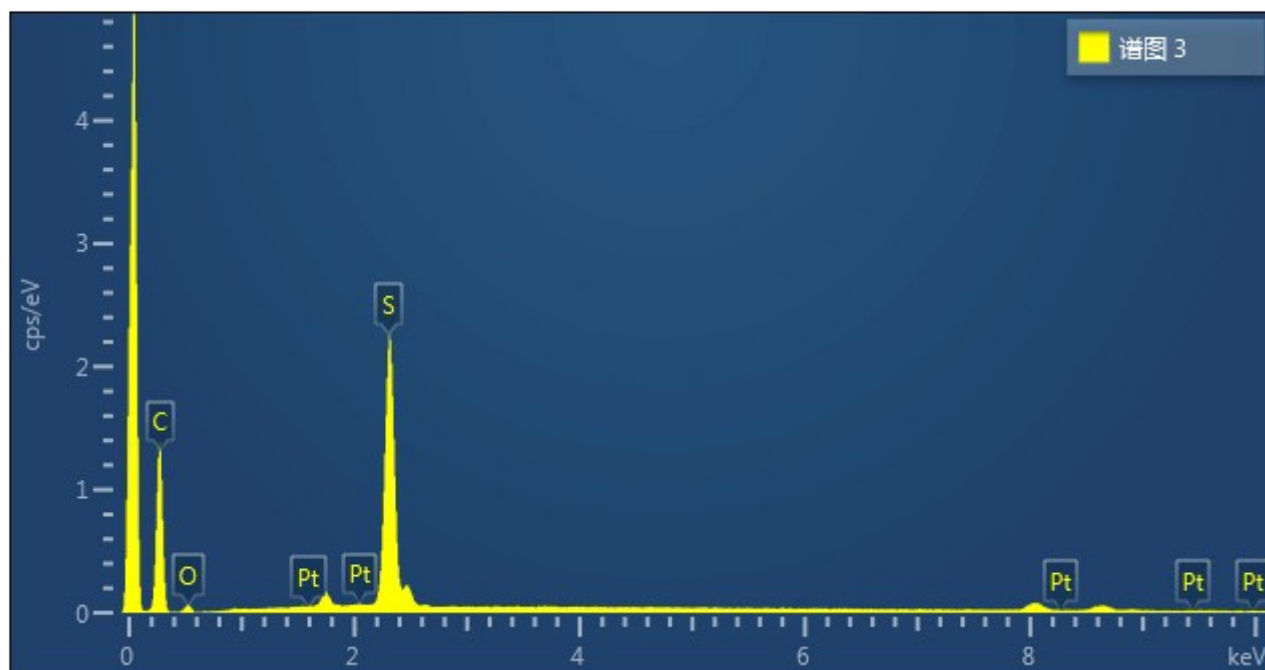


Figure S1. EDS elemental analysis spectrum of P(dbm)PtPyTPA1.

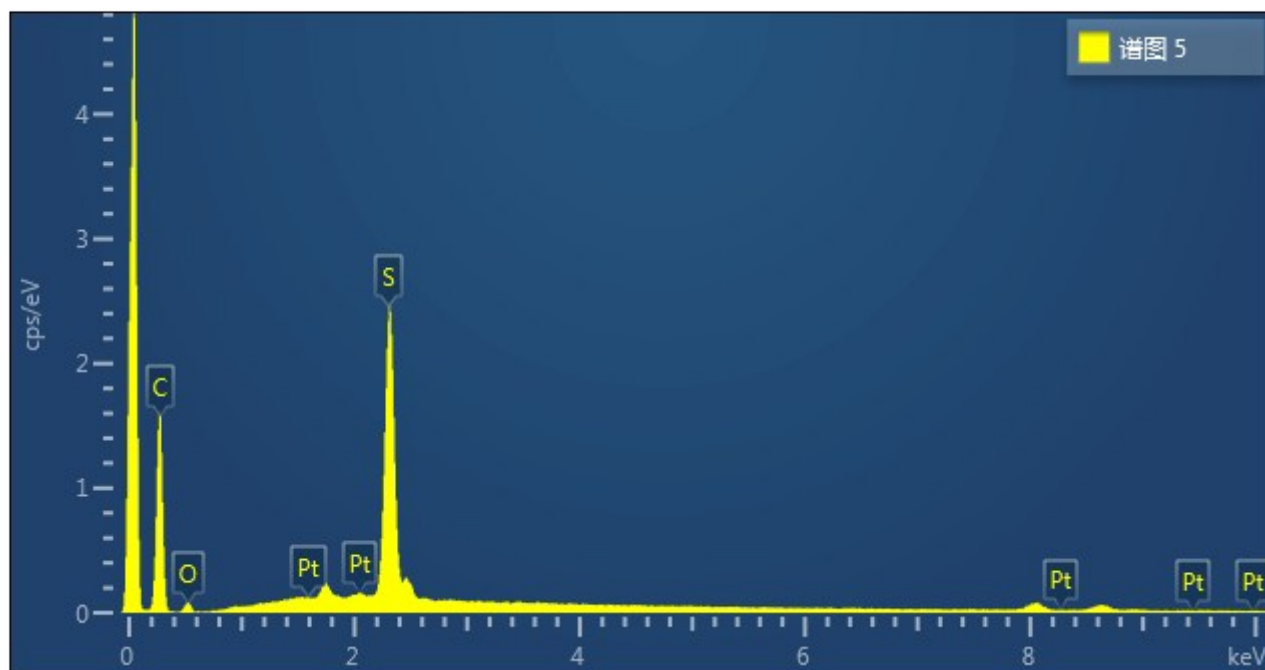


Figure S2. EDS elemental analysis spectrum of P(dbm)PtPyTPA2.

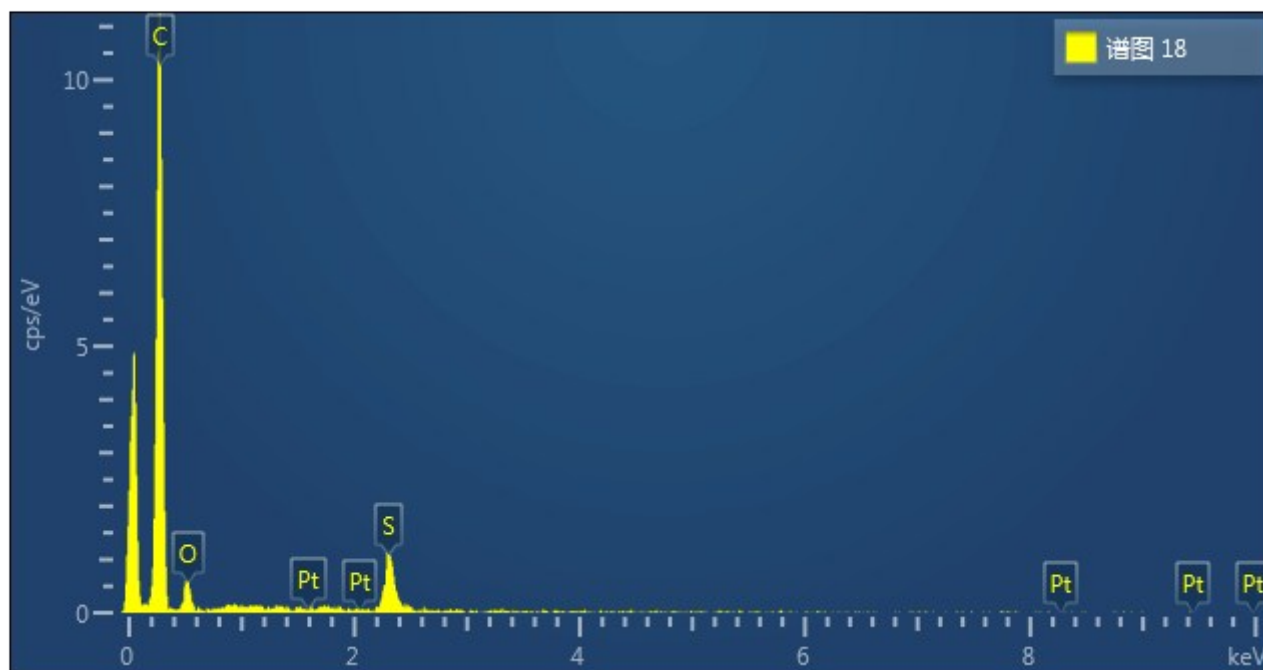


Figure S3. EDS elemental analysis spectrum of P(dbm)PtPyTPA5.

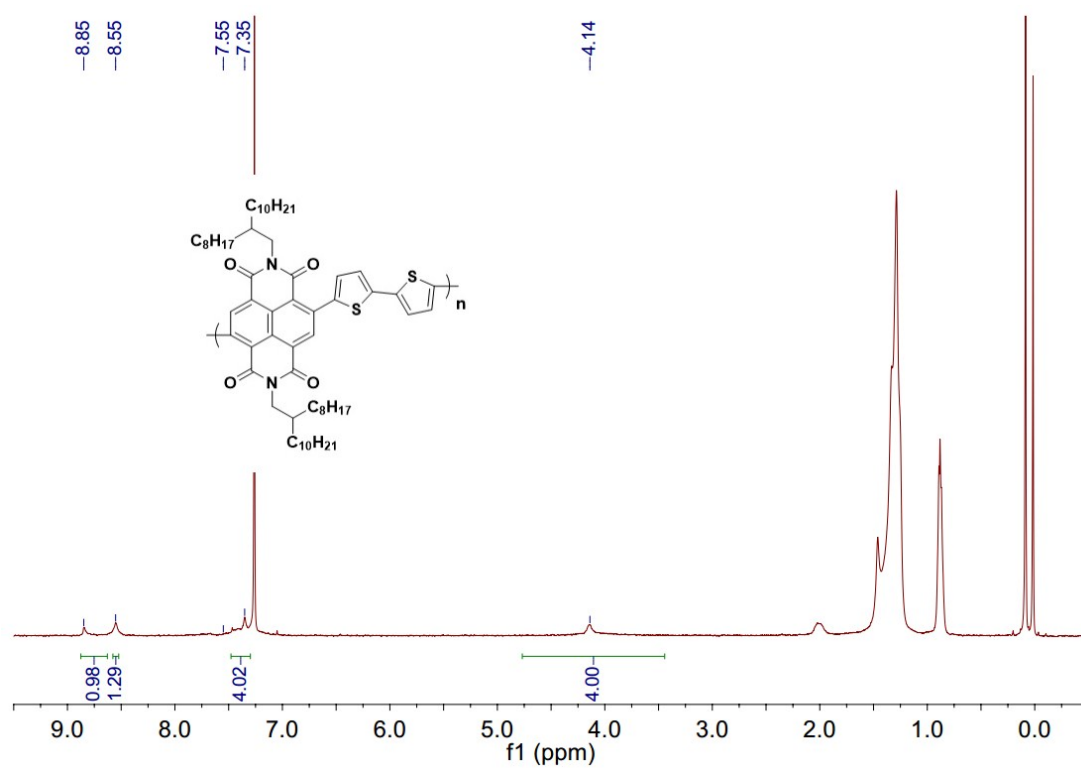


Figure S4. ^1H NMR spectra of PNDIT2.

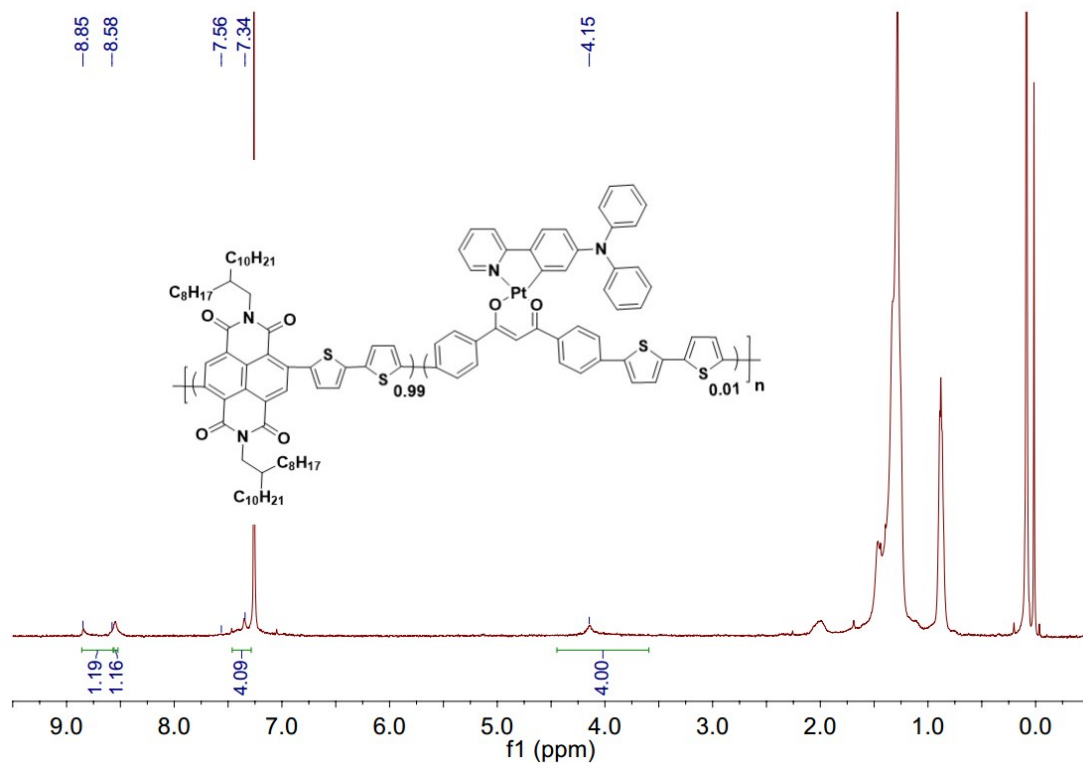


Figure S5. ¹H NMR spectra of P(dbm)PtPyTPA1.

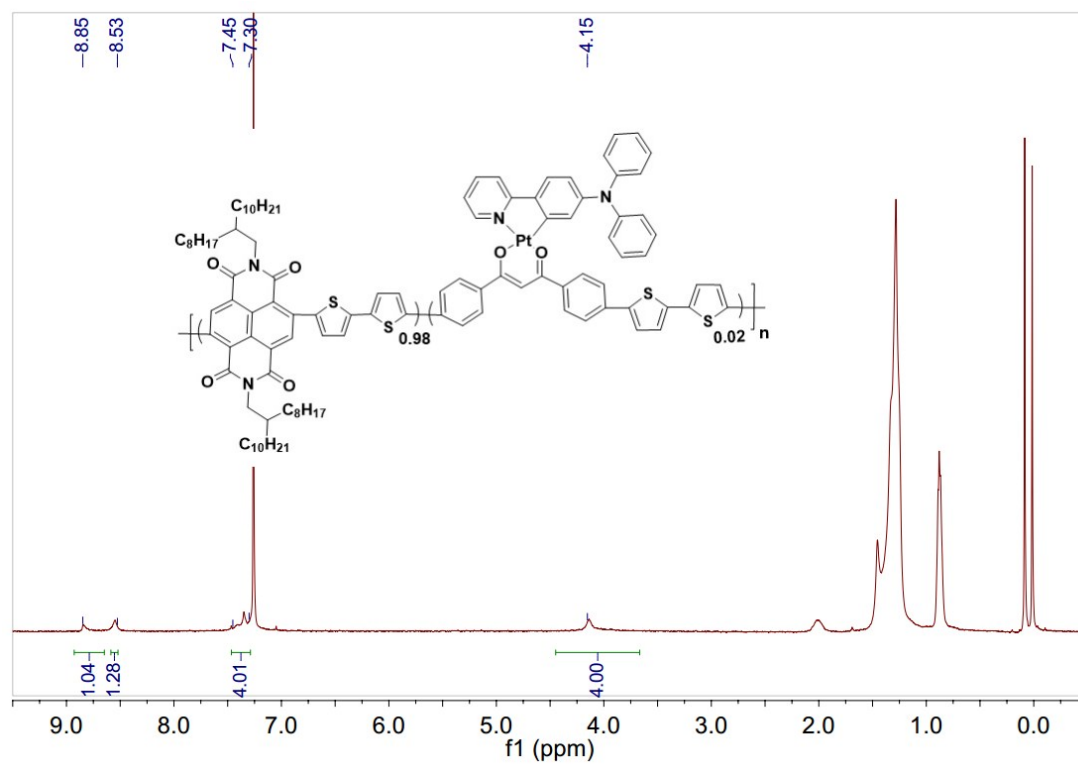


Figure S6. ¹H NMR spectra of P(dbm)PtPyTPA2.

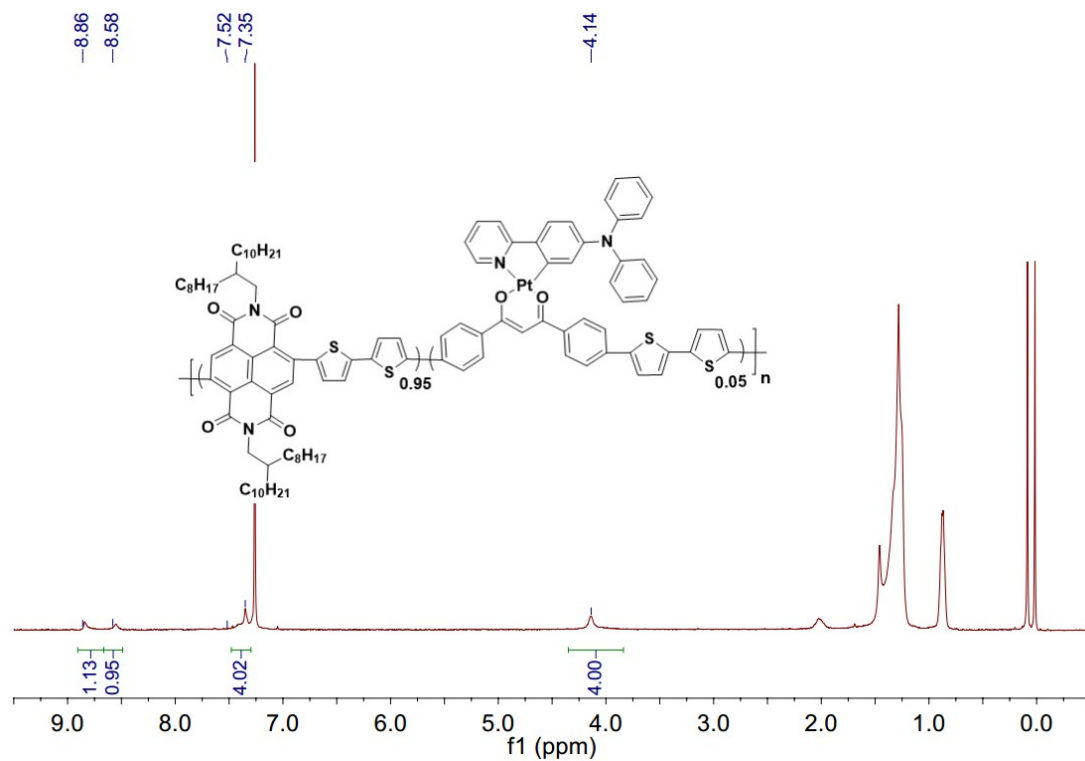


Figure S7. ^1H NMR spectra of P(dbm)PtPyTPA5.

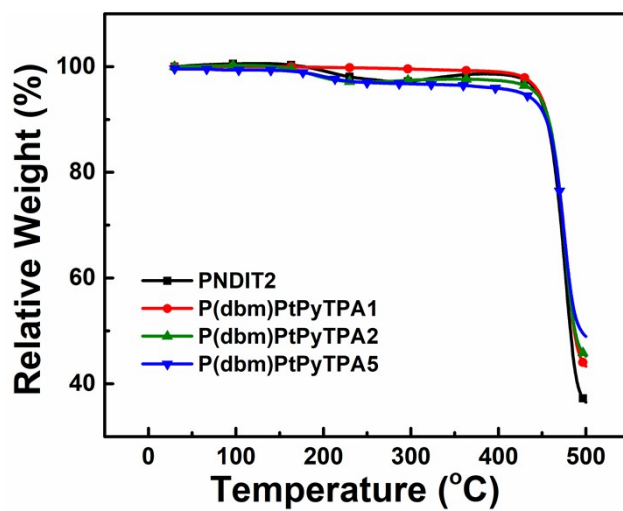


Figure S8. Thermogravimetric analysis (TGA) curves for polymer acceptors.

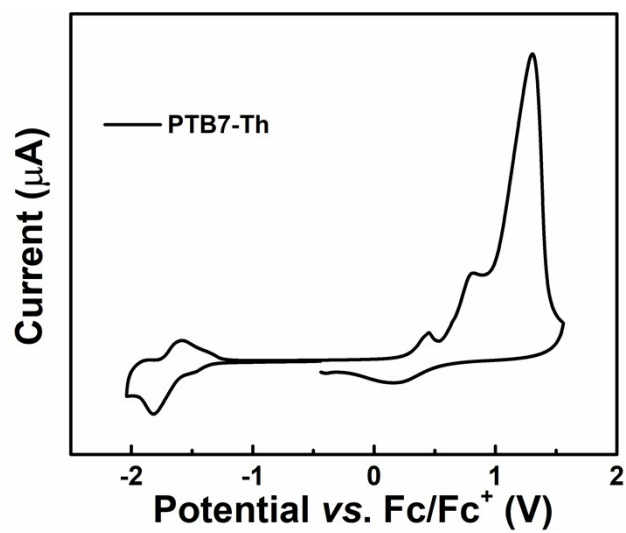


Figure S9. Cyclic voltammogram of PTB7-Th.

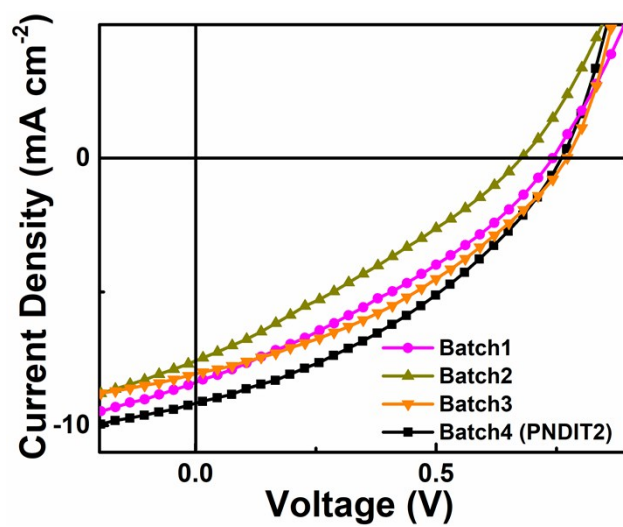


Figure S10. *J*-*V* curves of different batches of PNDIT2.

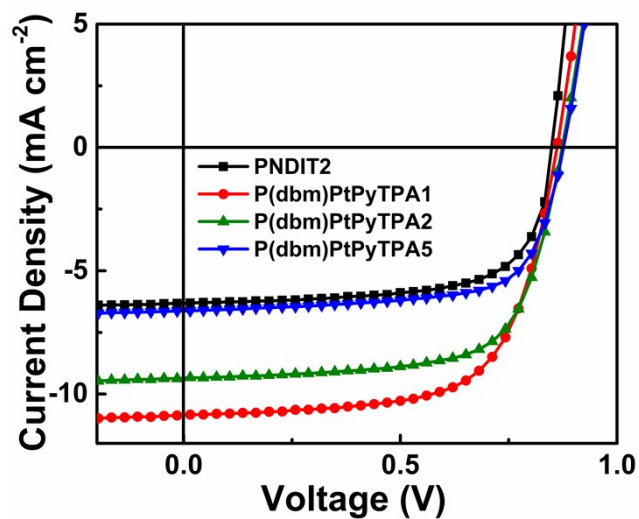


Figure S11. *J-V* curves of PBDB-T:P(dbm)PtPyTPAx ($x=0, 1, 2$ and 5) in conventional device structure.

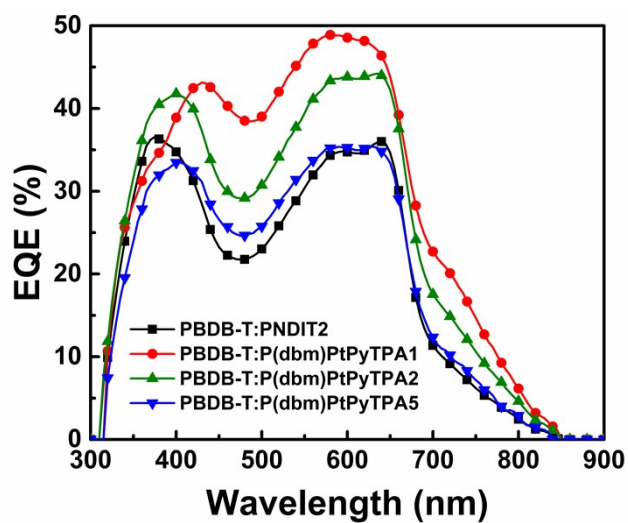


Figure S12. EQE spectra of PBDB-T:P(dbm)PtPyTPAx ($x=0, 1, 2$ and 5).

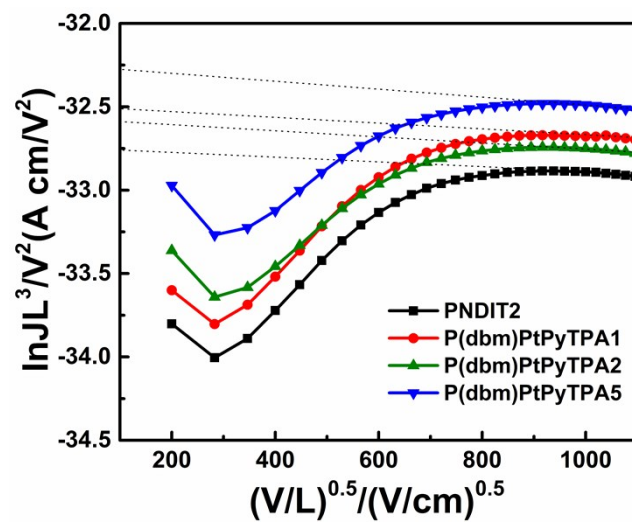


Figure S13. J - V curves of neat polymer acceptor in electron-only device structure under dark condition.

Table S1. Theoretical weight ratio of Pt element in P(dbm)PtPyTPAx (x = 1, 2, 5) and the practical values measured by EDS.

polymer acceptor	theoretical values (wt%)	values measured by EDS (wt%)
P(dbm)PtPyTPA1	0.20	0.17
P(dbm)PtPyTPA2	0.39	0.34
P(dbm)PtPyTPA5	0.98	0.64

Table S2. The key photovoltaic parameters of conventional devices based on PBDB-T:P(dbm)PtPyTPAx (x = 0, 1, 2 and 5) with average PCE collected from over 10 devices.

Active Layer	V_{oc} [V]	J_{sc} [mA cm ²]	FF [%]	PCE _{max} [%]	PCE _{ave} [%]
PBDB-T:	0.86	6.47	67.93	3.79	3.62
PNDIT2	(0.86±0)	(6.17±0.30)	(68.06±0.44)		
PBDB-T:	0.86	10.84	65.99	6.18	6.01
P(dbm)PtPyTPA1	(0.86±0)	(10.57±0.55)	(65.71±1.52)		
PBDB-T:	0.86	9.41	67.02	5.64	5.57
P(dbm)PtPyTPA2	(0.86±0)	(9.23±0.18)	(69.35±2.33)		
PBDB-T:	0.87	6.63	70.19	4.02	3.97
P(dbm)PtPyTPA5	(0.87±0)	(6.54±0.22)	(69.87±1.90)		

Table S3. Charge mobilities of polymer acceptor neat film and PTB7-Th:P(dbm)PtPyTPAx (x=0, 1, 2 and 5) blends, data achieved by an average of 6 devices.

	μ_h [cm ² V ⁻¹ s ⁻¹]	μ_e [cm ² V ⁻¹ s ⁻¹]
PNDIT2	-	1.98×10 ⁻⁵
P(dbm)PtPyTPA1	-	2.35×10 ⁻⁵
P(dbm)PtPyTPA2	-	2.55×10 ⁻⁵
P(dbm)PtPyTPA5	-	3.29×10 ⁻⁵
PTB7-Th: PNDIT2	2.49×10 ⁻⁴	3.30×10 ⁻⁵
PTB7-Th: P(dbm)PtPyTPA1	3.61×10 ⁻⁴	4.29×10 ⁻⁵
PTB7-Th: P(dbm)PtPyTPA2	5.07×10 ⁻⁴	4.98×10 ⁻⁵
PTB7-Th: P(dbm)PtPyTPA5	6.25×10 ⁻⁴	5.61×10 ⁻⁵